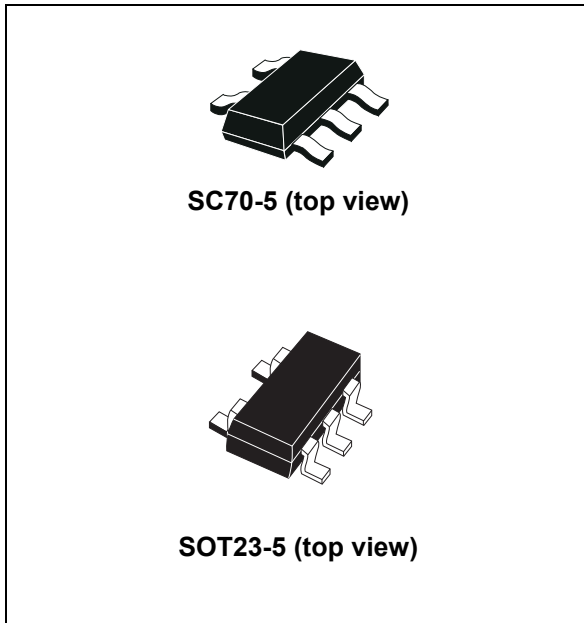


## Rail-to-rail 0.9 V nanopower comparator

Datasheet - production data



### Description

The TS881 device is a single comparator featuring ultra low supply current (210 nA typical with output high,  $V_{CC} = 1.2\text{ V}$ , no load) with rail-to-rail input and output capability. The performance of this comparator allows it to be used in a wide range of portable applications. The TS881 device minimizes battery supply leakage and therefore enhances battery lifetime.

Operating from 0.85 V to 5.5 V supply voltage, this comparator can be used over a wide temperature range (-40 to +125 °C) keeping the current consumption at an ultra low level.

The TS881 device is available in the SC70-5 and the SOT23-5 package, allowing great space saving on the PCB.

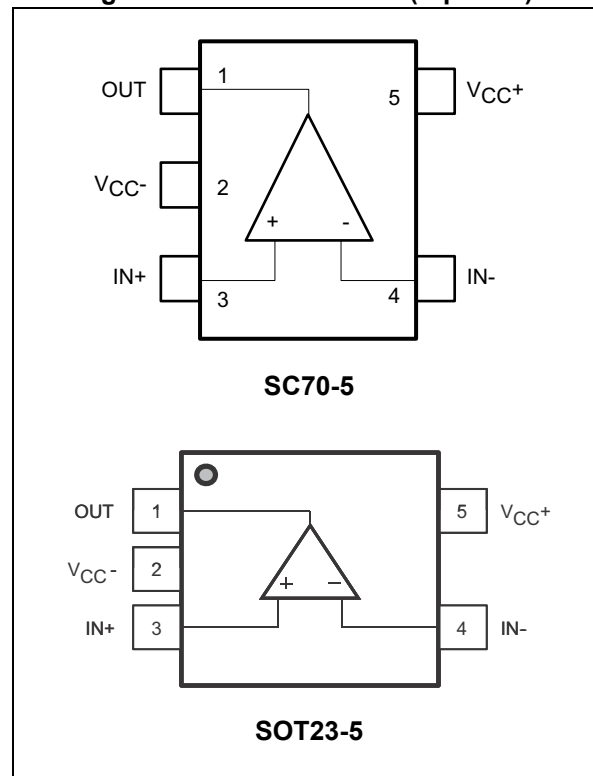
### Features

- Ultra low current consumption: 210 nA typ.
- Propagation delay: 2  $\mu\text{s}$  typ.
- Rail-to-rail inputs
- Push-pull output
- Supply operation from 0.85 V to 5.5 V
- Wide temperature range: -40 to +125 °C
- ESD tolerance: 8 kV HBM / 300 V MM
- SMD package

### Applications

- Portable systems
- Signal conditioning
- Medical

Figure 1. Pin connections (top view)



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# 1 Absolute maximum ratings and operating conditions

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage <sup>(1)</sup>	6	V
$V_{ID}$	Differential input voltage <sup>(2)</sup>	±6	V
$V_{IN}$	Input voltage range	$(V_{CC-}) - 0.3$ to $(V_{CC+}) + 0.3$	V
$R_{THJA}$	Thermal resistance junction-to-ambient <sup>(3)</sup>		°C/W
	SC70-5	205	
	SOT23-5	250	
$T_{STG}$	Storage temperature	-65 to +150	°C
$T_J$	Junction temperature	150	°C
$T_{LEAD}$	Lead temperature (soldering 10 seconds)	260	°C
ESD	Human body model (HBM) <sup>(4)</sup>	8000	kV
	Machine model (MM) <sup>(5)</sup>	300	V
	Charged device model (CDM) <sup>(6)</sup>	1300	
	Latch-up immunity	200	mA

1. All voltage values, except differential voltages, are referenced to  $V_{CC-}$ .  $V_{CC}$  is defined as the difference between  $V_{CC+}$  and  $V_{CC-}$ .
2. The magnitude of input and output voltages must never exceed the supply rail ±0.3 V.
3. Short-circuits can cause excessive heating. These values are typical.
4. According to JEDEC standard JESD22-A114F.
5. According to JEDEC standard JESD22-A115A.
6. According to ANSI/ESD STM5.3.1.

**Table 2. Operating conditions**

Symbol	Parameter	Value	Unit
$T_{oper}$	Operating temperature range		°C
	$0.85\text{ V} < V_{CC} < 5.5\text{ V}$	-40 to +85	
	$1.1\text{ V} < V_{CC} < 5.5\text{ V}$	-40 to +125	
$V_{CC}$	Supply voltage		V
	$-40\text{ °C} < T_{amb} < +85\text{ °C}$	0.85 to 5.5	
	$-40\text{ °C} < T_{amb} < +125\text{ °C}$	1.1 to 5.5	
$V_{ICM}$	Common mode input voltage range		V
	$0.85\text{ V} < V_{CC} < 5.5\text{ V}$	-0.2 to +0.2 and $V_{CC-} - 0.2$ to $V_{CC+} + 0.2$	
	$-40\text{ °C} < T_{amb} < +85\text{ °C}$		
	$1.1\text{ V} < V_{CC} < 5.5\text{ V}$	$V_{CC-} - 0.2$ to $V_{CC+} + 0.2$ $V_{CC-}$ to $V_{CC+} + 0.2$	
	$-40\text{ °C} < T_{amb} < +85\text{ °C}$		
	$-40\text{ °C} < T_{amb} < +125\text{ °C}$		

## 2 Electrical characteristics

Table 3.  $V_{CC} = +0.9\text{ V}$ ,  $T_{amb} = +25\text{ °C}$ ,  $V_{ICM} = 0\text{ V}$  (unless otherwise specified)<sup>(1)</sup>

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IO}$	Input offset voltage <sup>(2)</sup>	$-40\text{ °C} < T_{amb} < +85\text{ °C}$	-10 -12	1	10 12	mV
$\Delta V_{IO}$	Input offset voltage drift	$-40\text{ °C} < T_{amb} < +85\text{ °C}$		4.6		$\mu\text{V}/\text{°C}$
$V_{HYST}$	Input hysteresis voltage <sup>(3)</sup>	$-40\text{ °C} < T_{amb} < +85\text{ °C}$	1.0	2.4	4.2	mV
$I_{IO}$	Input offset current <sup>(4)</sup>	$-40\text{ °C} < T_{amb} < +85\text{ °C}$	-10 -100		10 100	pA
$I_{IB}$	Input bias current <sup>(4)</sup>	$-40\text{ °C} < T_{amb} < +85\text{ °C}$	-10 -100		10 100	pA
$I_{CC}$	Supply current per operator	No load, output low, $V_{ID} = -0.1\text{ V}$ $-40\text{ °C} < T_{amb} < +85\text{ °C}$		300	400 450	nA
		No load, output high, $V_{ID} = +0.1\text{ V}$ $-40\text{ °C} < T_{amb} < +85\text{ °C}$		260	350 400	
$I_{SC}$	Short-circuit current	Source Sink		0.2 0.4		mA
$V_{OH}$	Output voltage high	$I_{source} = 50\text{ }\mu\text{A}$ $-40\text{ °C} < T_{amb} < +85\text{ °C}$	0.85 0.83	0.87		V
$V_{OL}$	Output voltage low	$I_{sink} = 50\text{ }\mu\text{A}$ $-40\text{ °C} < T_{amb} < +85\text{ °C}$		20	50 70	mV
$T_{PLH}$	Propagation delay (low to high)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ °C} < T_{amb} < +85\text{ °C}$		7.2	14 16	$\mu\text{s}$
		Overdrive = 100 mV $-40\text{ °C} < T_{amb} < +85\text{ °C}$		3.3	5.0 5.5	
$T_{PHL}$	Propagation delay (high to low)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ °C} < T_{amb} < +85\text{ °C}$		6.0	11 12	$\mu\text{s}$
		Overdrive = 100 mV $-40\text{ °C} < T_{amb} < +85\text{ °C}$		2.5	4.5 5.0	
$T_R$	Rise time (10% to 90%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		160		ns
$T_F$	Fall time (90% to 10%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		140		ns
$T_{ON}$	Power-up time			1.1	1.7	ms

1. All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.
2. The offset is defined as the average value of positive and negative trip points (input voltage differences requested to change the output state in each direction).
3. The hysteresis is a built-in feature of the TS881 device. It is defined as the voltage difference between the trip points.
4. Maximum values are guaranteed by design.

Table 4.  $V_{CC} = +1.2\text{ V}$ ,  $T_{amb} = +25\text{ }^{\circ}\text{C}$ ,  $V_{ICM} = V_{CC}/2$  (unless otherwise specified)<sup>(1)</sup>

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IO}$	Input offset voltage <sup>(2)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-6	1	6	mV
$\Delta V_{IO}$	Input offset voltage drift	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		3		$\mu\text{V}/^{\circ}\text{C}$
$V_{HYST}$	Input hysteresis voltage <sup>(3)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	1.6	2.4	4.2	mV
$I_{IO}$	Input offset current <sup>(4)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-10 -100		10 100	pA
$I_{IB}$	Input bias current <sup>(4)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-10 -100	1	10 100	pA
$I_{CC}$	Supply current per operator	No load, output low, $V_{ID} = -0.1\text{ V}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$  No load, output high, $V_{ID} = +0.1\text{ V}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		300  210	450 500 1050  350 400 950	nA
$I_{SC}$	Short-circuit current	Source Sink		1.4 1.0		mA
$V_{OH}$	Output voltage high	$I_{source} = 0.2\text{ mA}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	1.13 1.10 1.00	1.15		V
$V_{OL}$	Output voltage low	$I_{sink} = 0.2\text{ mA}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		40	50 60 70	mV
CMRR	Common mode rejection ratio	$0 < V_{ICM} < V_{CC}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	50	68		dB
$T_{PLH}$	Propagation delay (low to high)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$  Overdrive = 100 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		6  2.2	11 13  3.1 3.4	$\mu\text{s}$
$T_{PHL}$	Propagation delay (high to low)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$  Overdrive = 100 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		5.1  2.0	8 10  2.6 3.1	$\mu\text{s}$
$T_R$	Rise time (10% to 90%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		100		ns
$T_F$	Fall time (90% to 10%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		110		ns
$T_{ON}$	Power-up time			1.0	1.5	ms

1. All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.
2. The offset is defined as the average value of positive and negative trip points (input voltage differences requested to change the output state in each direction).
3. The hysteresis is a built-in feature of the TS881 device. It is defined as the voltage difference between the trip points.
4. Maximum values are guaranteed by design.

**Table 5.  $V_{CC} = +2.7\text{ V}$ ,  $T_{amb} = +25\text{ }^\circ\text{C}$ ,  $V_{ICM} = V_{CC}/2$  (unless otherwise specified)<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IO}$	Input offset voltage <sup>(2)</sup>	$-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	-6	1	6	mV
$\Delta V_{IO}$	Input offset voltage drift	$-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$		3		$\mu\text{V}/^\circ\text{C}$
$V_{HYST}$	Input hysteresis voltage <sup>(3)</sup>	$-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	1.6	2.7	4.2	mV
$I_{IO}$	Input offset current <sup>(4)</sup>	$-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	-10 -100		10 100	pA
$I_{IB}$	Input bias current <sup>(4)</sup>	$-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	-10 -100	1	10 100	pA
$I_{CC}$	Supply current per operator	No load, output low, $V_{ID} = -0.1\text{ V}$ $-40\text{ }^\circ\text{C} < T_{amb} < +85\text{ }^\circ\text{C}$ $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$ No load, output high, $V_{ID} = +0.1\text{ V}$ $-40\text{ }^\circ\text{C} < T_{amb} < +85\text{ }^\circ\text{C}$ $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$		310 220	450 500 1150 350 400 1050	nA
$I_{SC}$	Short-circuit current	Source Sink		12 10		mA
$V_{OH}$	Output voltage high	$I_{source} = 2\text{ mA}$ $-40\text{ }^\circ\text{C} < T_{amb} < +85\text{ }^\circ\text{C}$ $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	2.48 2.40 2.10	2.51		V
$V_{OL}$	Output voltage low	$I_{sink} = 2\text{ mA}$ $-40\text{ }^\circ\text{C} < T_{amb} < +85\text{ }^\circ\text{C}$ $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$		140	210 230 310	mV
CMRR	Common mode rejection ratio	$0 < V_{ICM} < V_{CC}$ $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$	55	74		dB
$T_{PLH}$	Propagation delay (low to high)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$ Overdrive = 100 mV $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$		6.3 2.4	12 13 3.0 3.7	$\mu\text{s}$
$T_{PHL}$	Propagation delay (high to low)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$ Overdrive = 100 mV $-40\text{ }^\circ\text{C} < T_{amb} < +125\text{ }^\circ\text{C}$		6.4 2.3	12 14 3.0 3.7	$\mu\text{s}$
$T_R$	Rise time (10% to 90%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		120		ns
$T_F$	Fall time (90% to 10%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		130		ns
$T_{ON}$	Power-up time			0.9	1.5	ms

1. All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.
2. The offset is defined as the average value of positive and negative trip points (input voltage differences requested to change the output state in each direction).
3. The hysteresis is a built-in feature of the TS881. It is defined as the voltage difference between the trip points.
4. Maximum values are guaranteed by design.





Table 6.  $V_{CC} = +5\text{ V}$ ,  $T_{amb} = +25\text{ }^{\circ}\text{C}$ ,  $V_{ICM} = V_{CC}/2$  (unless otherwise specified)<sup>(1)</sup>

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IO}$	Input offset voltage <sup>(2)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-6	1	6	mV
$\Delta V_{IO}$	Input offset voltage drift	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		3		$\mu\text{V}/^{\circ}\text{C}$
$V_{HYST}$	Input hysteresis voltage <sup>(3)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	1.6	3.1	4.2	mV
$I_{IO}$	Input offset current <sup>(4)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-10 -100		10 100	$\mu\text{A}$
$I_{IB}$	Input bias current <sup>(4)</sup>	$-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	-10 -100	1	10 100	$\mu\text{A}$
$I_{CC}$	Supply current per operator	No load, output low, $V_{ID} = -0.1\text{ V}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$ No load, output high, $V_{ID} = +0.1\text{ V}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		350 250	500 750 1350 400 650 1250	nA
$I_{SC}$	Short-circuit current	Source Sink		32 36		mA
$V_{OH}$	Output voltage high	$I_{source} = 2\text{ mA}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	4.86 4.75 4.60	4.90		V
$V_{OL}$	Output voltage low	$I_{sink} = 2\text{ mA}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +85\text{ }^{\circ}\text{C}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		95	130 170 280	mV
CMRR	Common mode rejection ratio	$0 < V_{ICM} < V_{CC}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	55	78		dB
SVR	Supply voltage rejection	$\Delta V_{CC} = 1.2\text{ V to } 5\text{ V}$ $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$	65	80		dB
$T_{PLH}$	Propagation delay (low to high)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$ Overdrive = 100 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		7.8 2.6	13 22 3.4 4.1	$\mu\text{s}$
$T_{PHL}$	Propagation delay (high to low)	$f = 1\text{ kHz}$ , $C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$ Overdrive = 10 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$ Overdrive = 100 mV $-40\text{ }^{\circ}\text{C} < T_{amb} < +125\text{ }^{\circ}\text{C}$		8.9 2.7	16 19 3.5 4.2	$\mu\text{s}$
$T_R$	Rise time (10% to 90%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		160		ns
$T_F$	Fall time (90% to 10%)	$C_L = 30\text{ pF}$ , $R_L = 1\text{ M}\Omega$		150		ns
$T_{ON}$	Power-up time			1.1	1.5	ms

1. All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.
2. The offset is defined as the average value of positive and negative trip points (input voltage differences requested to change the output state in each direction).
3. The hysteresis is a built-in feature of the TS881 device. It is defined as the voltage difference between the trip points.
4. Maximum values are guaranteed by design.

Figure 2. Current consumption vs. supply voltage - output low

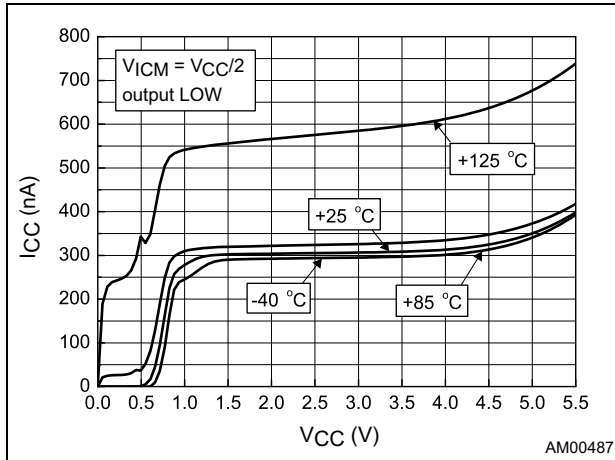


Figure 3. Current consumption vs. supply voltage - output high

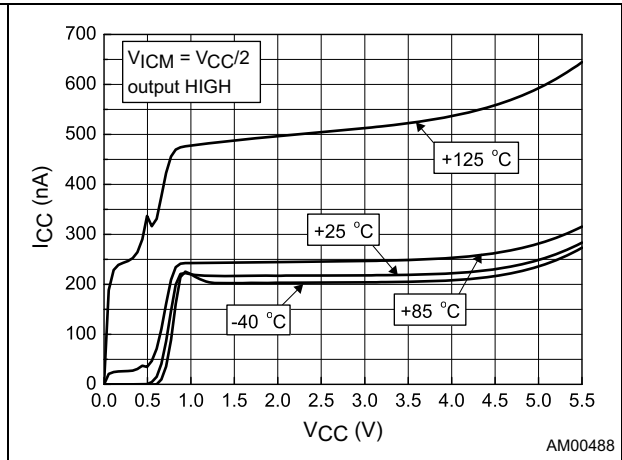


Figure 4. Current consumption vs. input common mode voltage at VCC = 1.2 V

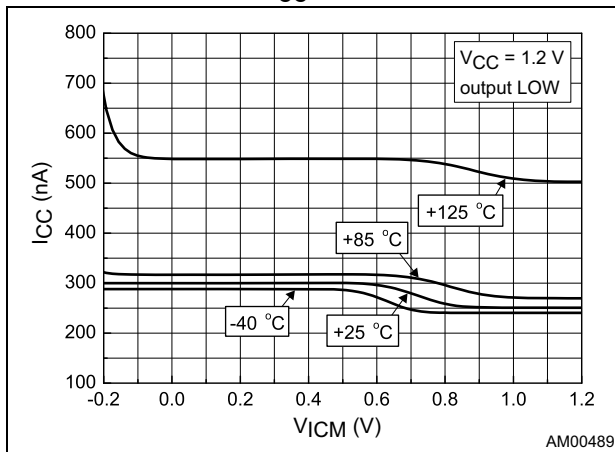


Figure 5. Current consumption vs. input common mode voltage at VCC = 5 V

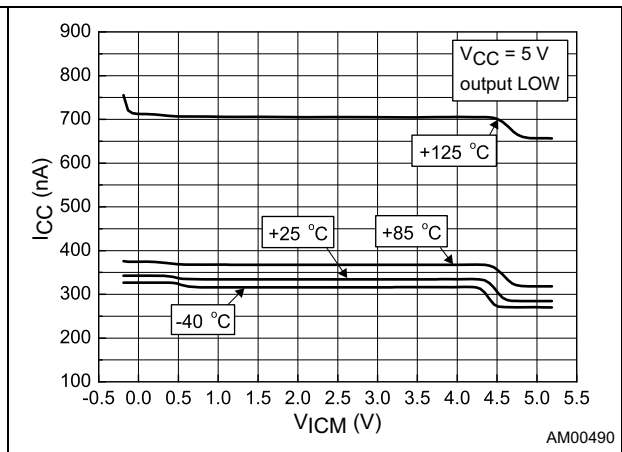


Figure 6. Current consumption vs. temperature

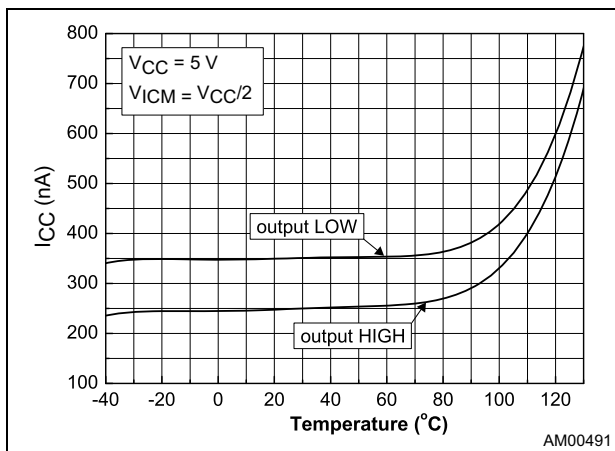
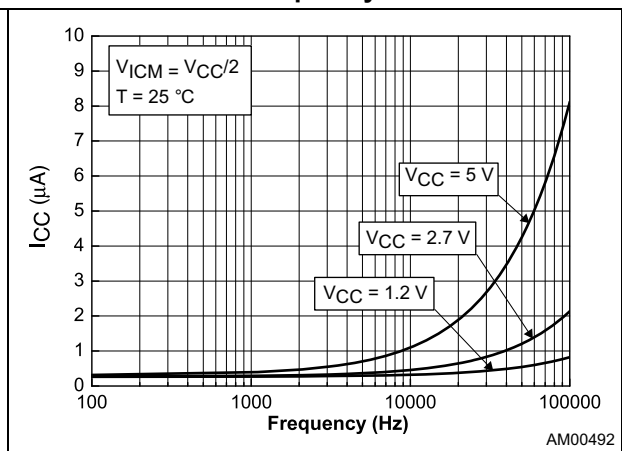
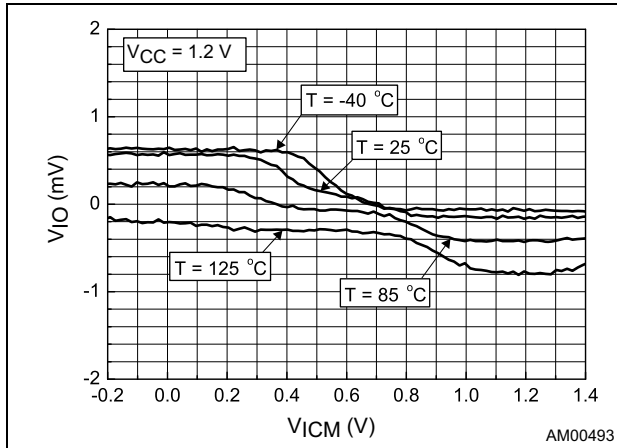


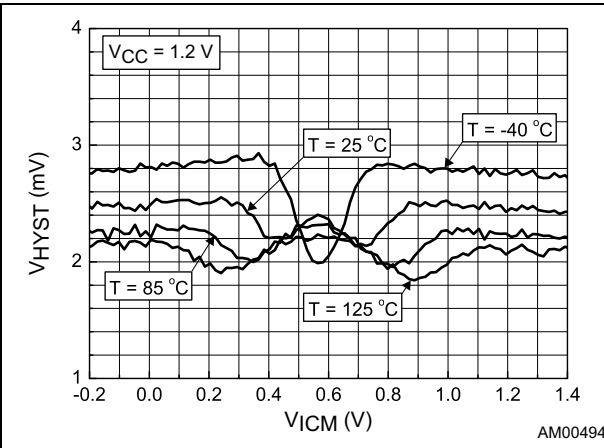
Figure 7. Current consumption vs. toggle frequency



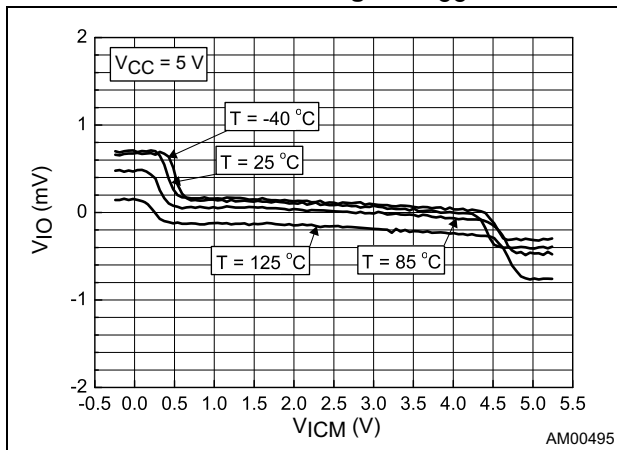
**Figure 8. Input offset voltage vs. input common mode voltage at  $V_{CC} = 1.2\text{ V}$**



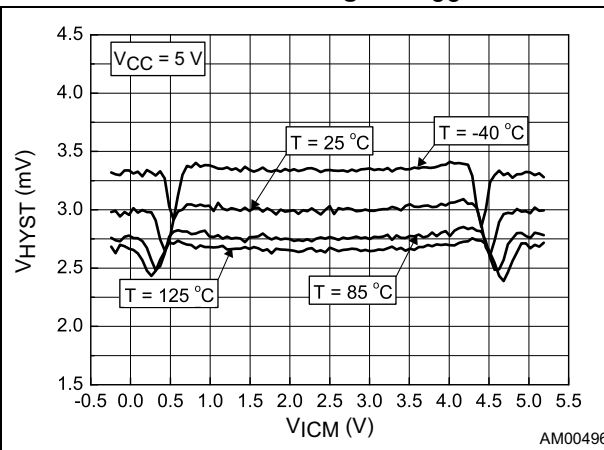
**Figure 9. Input hysteresis voltage vs. input common mode voltage at  $V_{CC} = 1.2\text{ V}$**



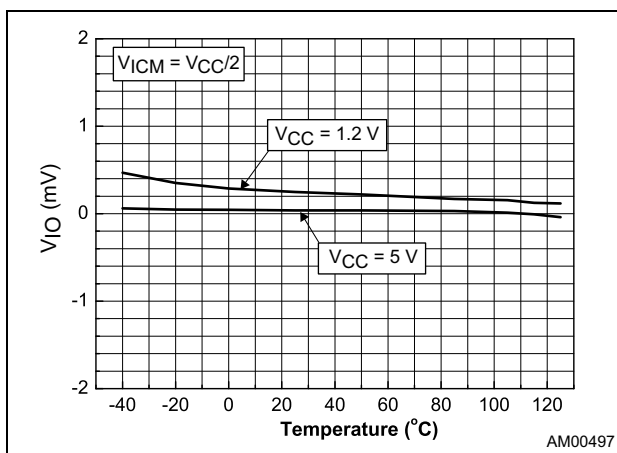
**Figure 10. Input offset voltage vs. input common mode voltage at  $V_{CC} = 5\text{ V}$**



**Figure 11. Input hysteresis voltage vs. input common mode voltage at  $V_{CC} = 5\text{ V}$**



**Figure 12. Input offset voltage vs. temperature**



**Figure 13. Input hysteresis voltage vs. temperature**

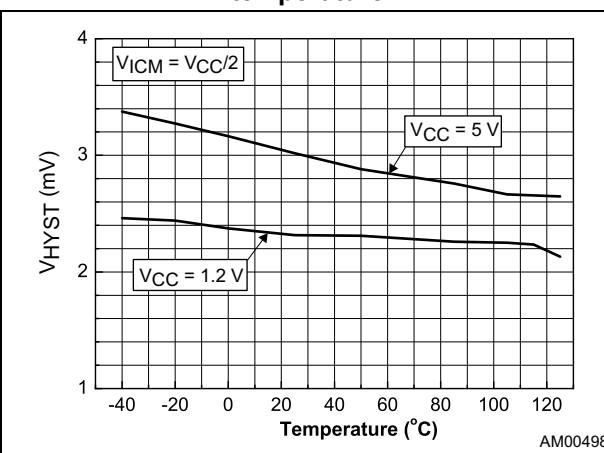


Figure 14. Output voltage drop vs. sink current at  $V_{CC} = 1.2\text{ V}$

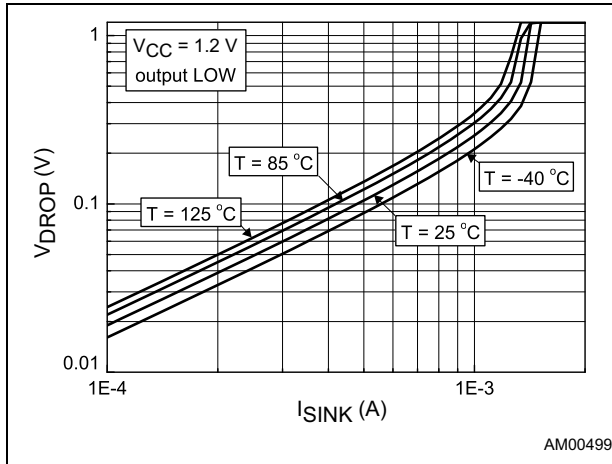


Figure 15. Output voltage drop vs. source current at  $V_{CC} = 1.2\text{ V}$

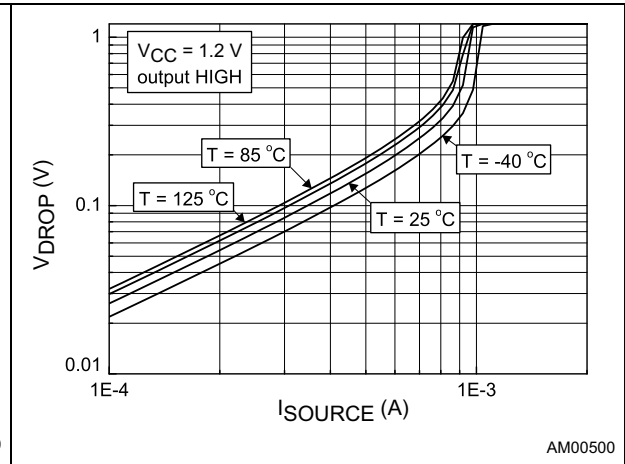


Figure 16. Output voltage drop vs. sink current at  $V_{CC} = 2.7\text{ V}$

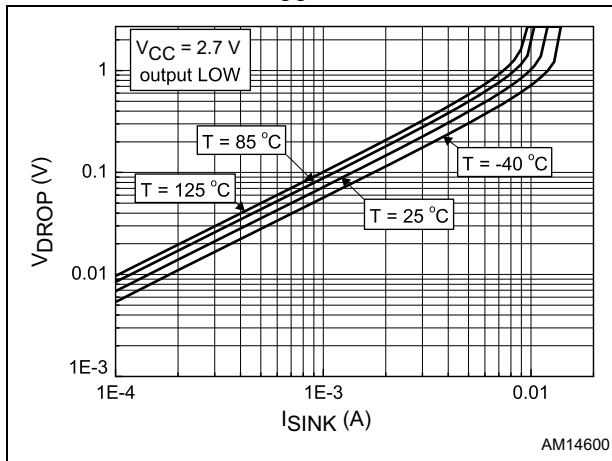


Figure 17. Output voltage drop vs. source current at  $V_{CC} = 2.7\text{ V}$

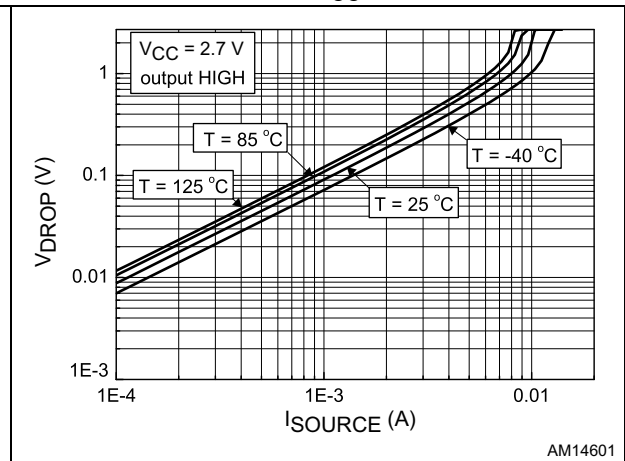


Figure 18. Output voltage drop vs. sink current at  $V_{CC} = 5\text{ V}$

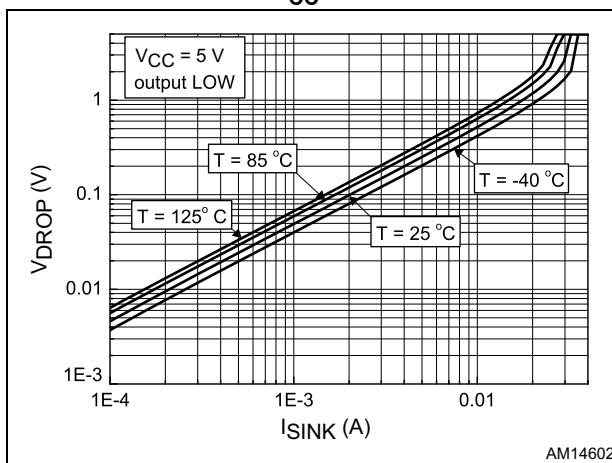


Figure 19. Output voltage drop vs. source current at  $V_{CC} = 5\text{ V}$

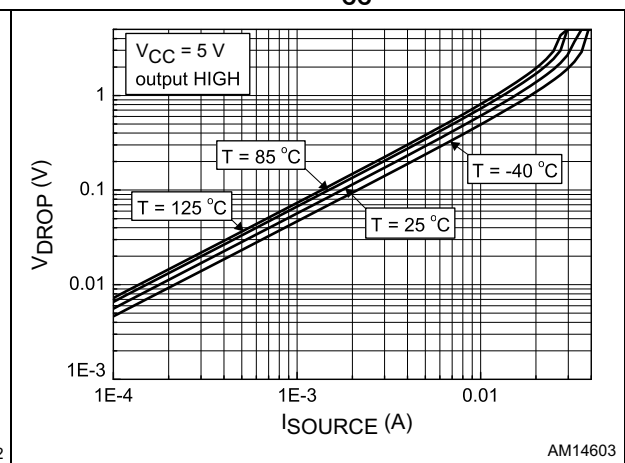


Figure 20. Propagation delay  $T_{PLH}$  vs. input common mode voltage at  $V_{CC} = 1.2\text{ V}$

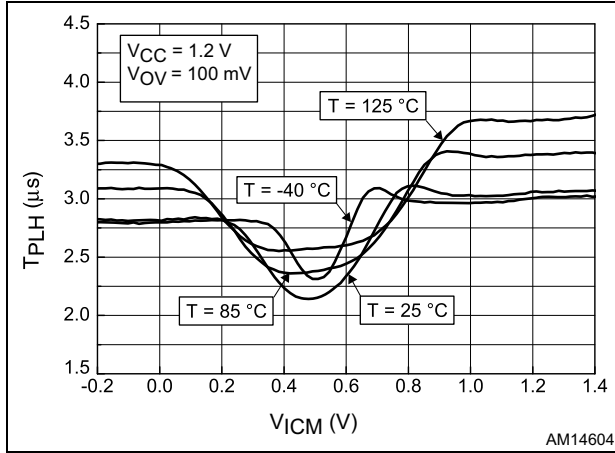


Figure 21. Propagation delay  $T_{PHL}$  vs. input common mode voltage at  $V_{CC} = 1.2\text{ V}$

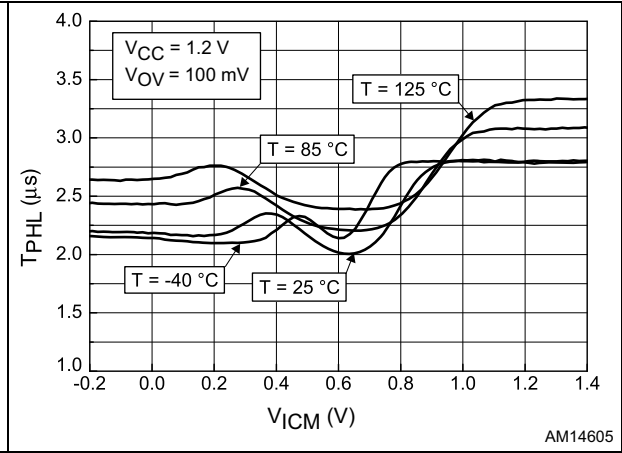


Figure 22. Propagation delay  $T_{PLH}$  vs. input common mode voltage at  $V_{CC} = 5\text{ V}$

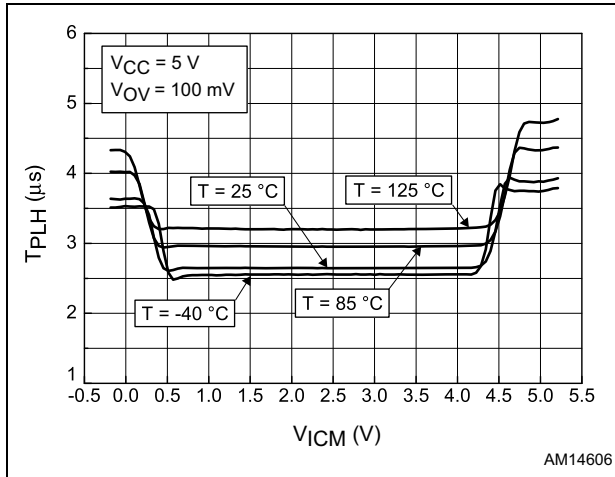


Figure 23. Propagation delay  $T_{PHL}$  vs. input common mode voltage at  $V_{CC} = 5\text{ V}$

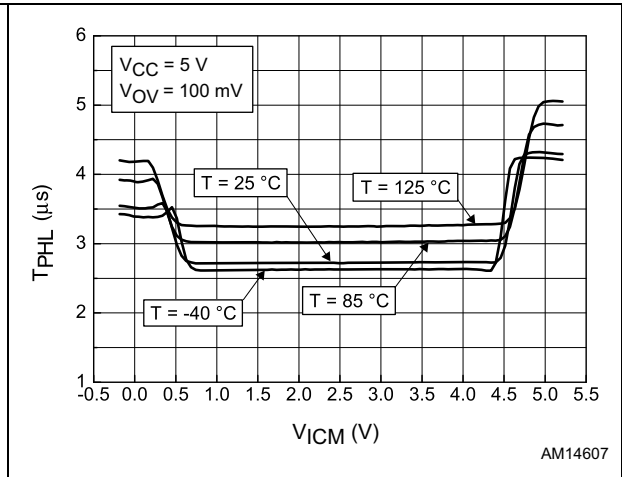


Figure 24. Propagation delay  $T_{PLH}$  vs. input signal overdrive at  $V_{CC} = 1.2\text{ V}$

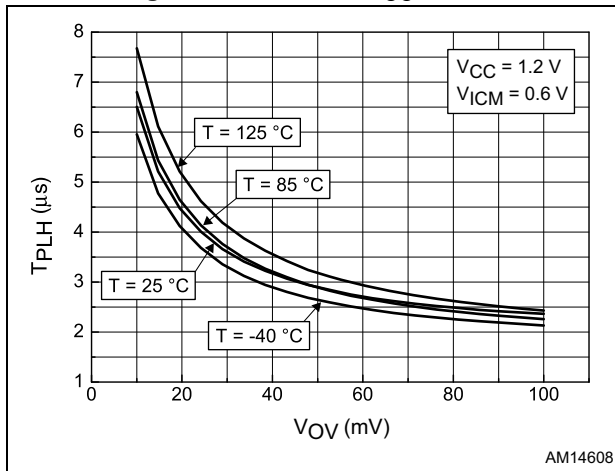


Figure 25. Propagation delay  $T_{PHL}$  vs. input signal overdrive at  $V_{CC} = 1.2\text{ V}$

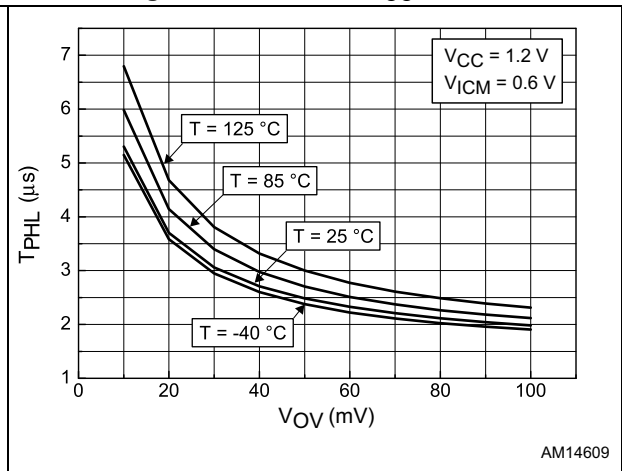


Figure 26. Propagation delay  $T_{PLH}$  vs. input signal overdrive at  $V_{CC} = 5\text{ V}$

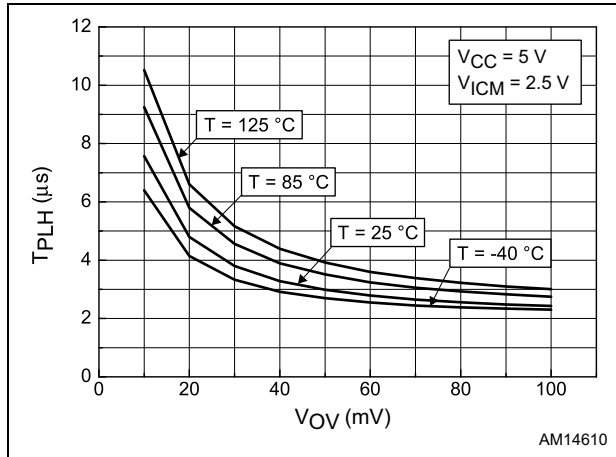


Figure 27. Propagation delay  $T_{PHL}$  vs. input signal overdrive at  $V_{CC} = 5\text{ V}$

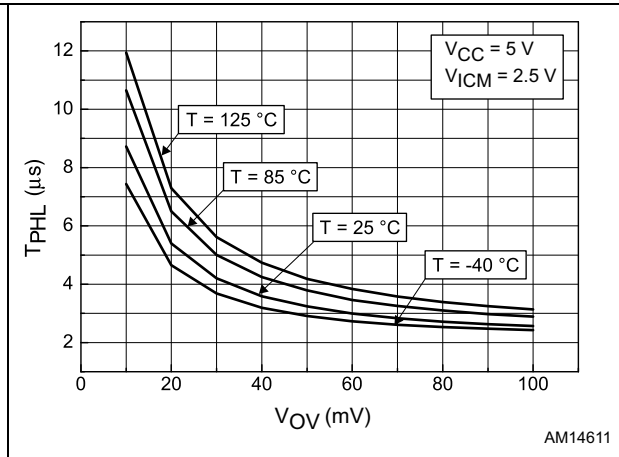


Figure 28. Propagation delay  $T_{PLH}$  vs. supply voltage for signal overdrive 10 mV

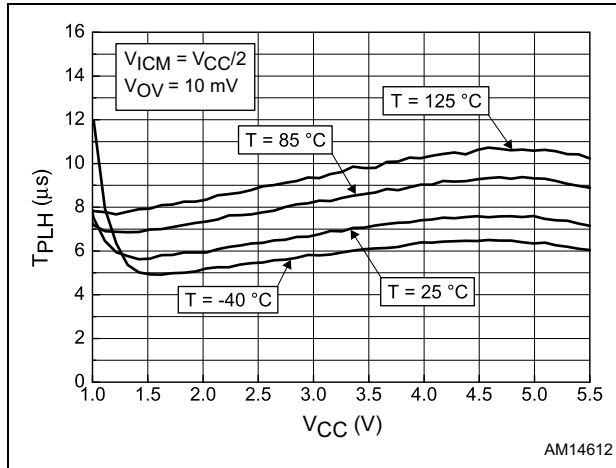


Figure 29. Propagation delay  $T_{PHL}$  vs. supply voltage for signal overdrive 10 mV

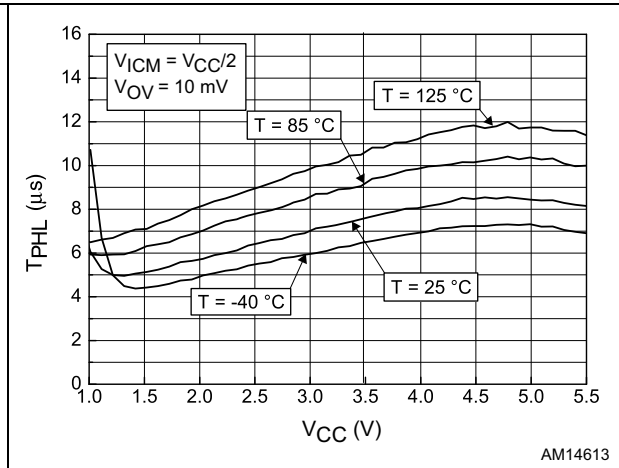


Figure 30. Propagation delay  $T_{PLH}$  vs. supply voltage for signal overdrive 100 mV

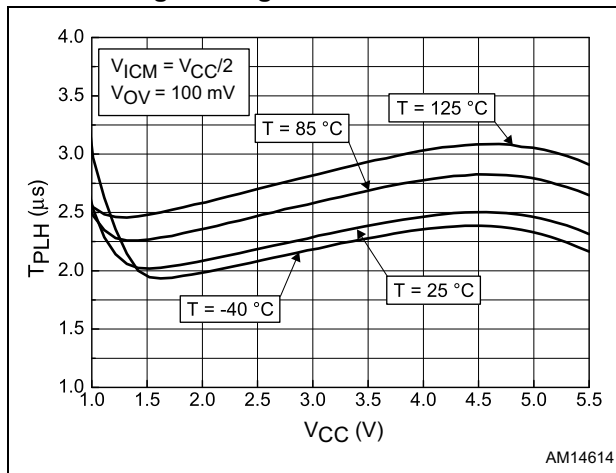


Figure 31. Propagation delay  $T_{PHL}$  vs. supply voltage for signal overdrive 100 mV

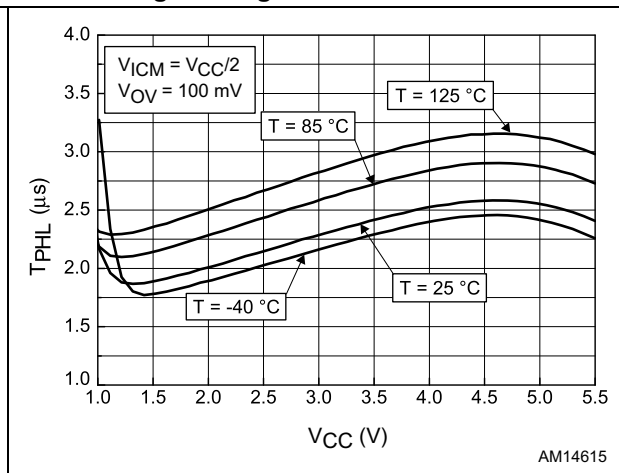


Figure 32. Propagation delay vs. temperature for signal overdrive 10 mV

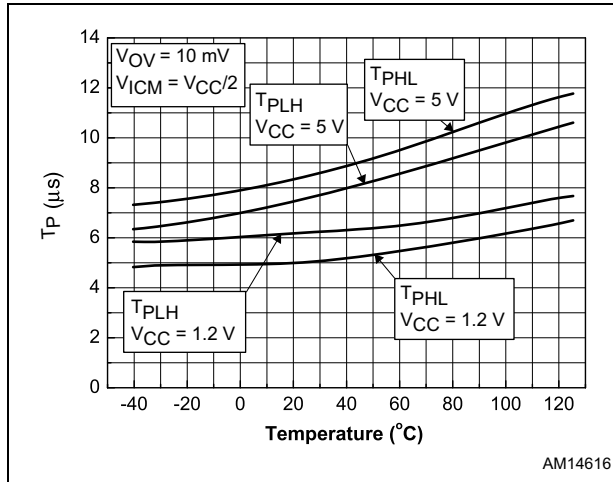


Figure 33. Propagation delay vs. temperature for signal overdrive 100 mV

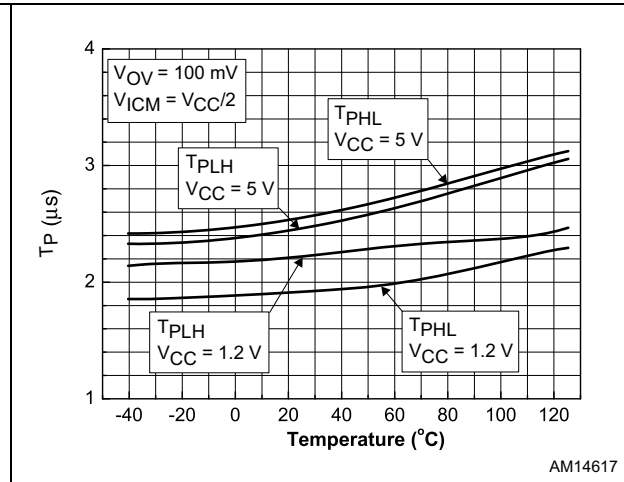


Figure 34. Input offset voltage vs. input common mode voltage at  $V_{CC} = 0.9 V$

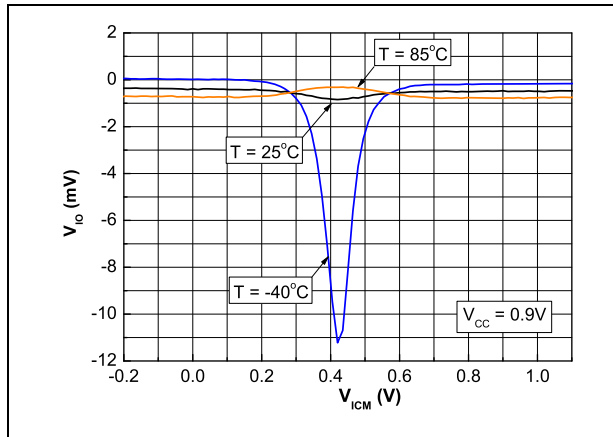


Figure 35. Input voltage hysteresis vs. input common mode voltage at  $V_{CC} = 0.9 V$

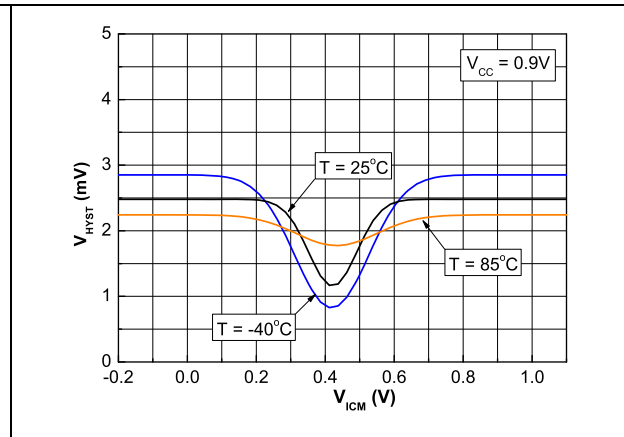


Figure 36. Output voltage drop vs. sink current at  $V_{CC} = 0.9 V$

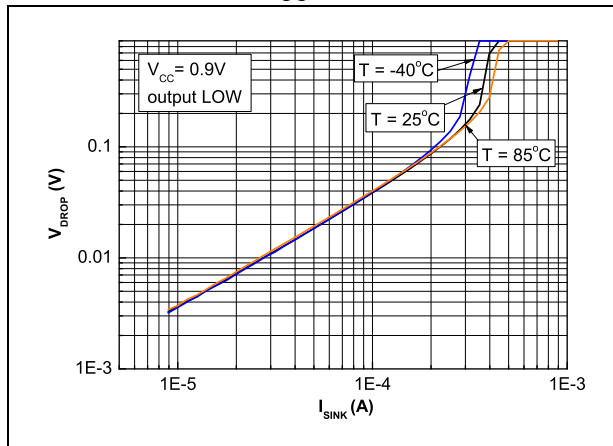
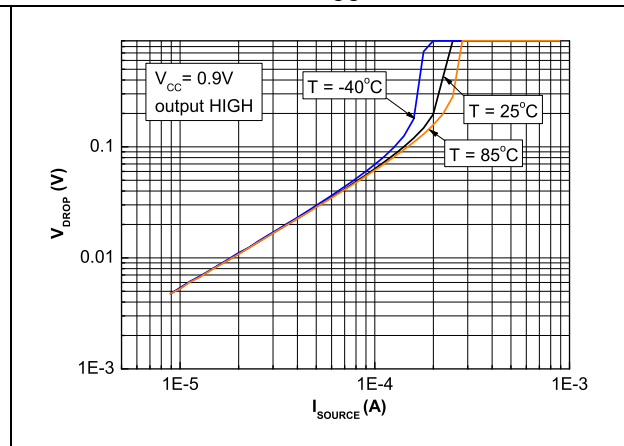
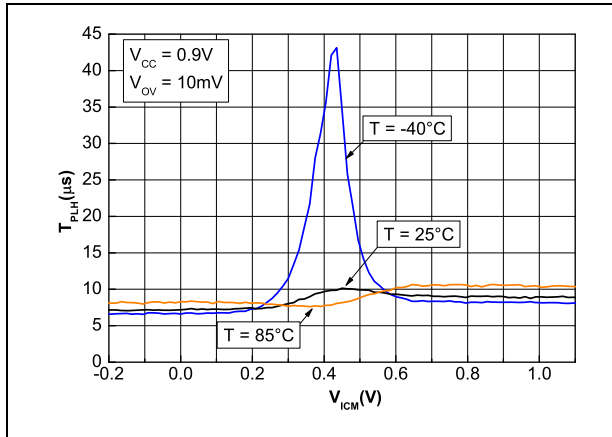


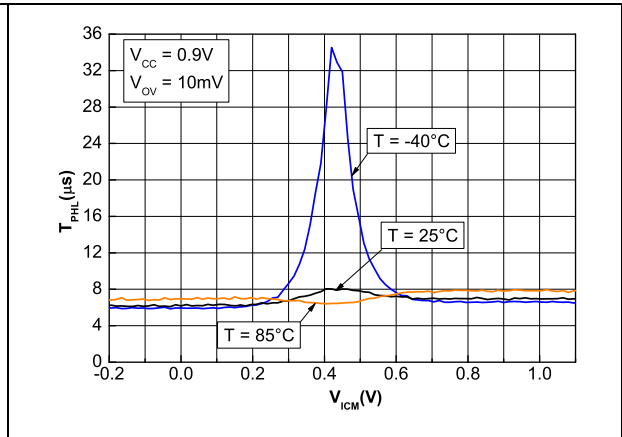
Figure 37. Output voltage drop vs. source current at  $V_{CC} = 0.9 V$



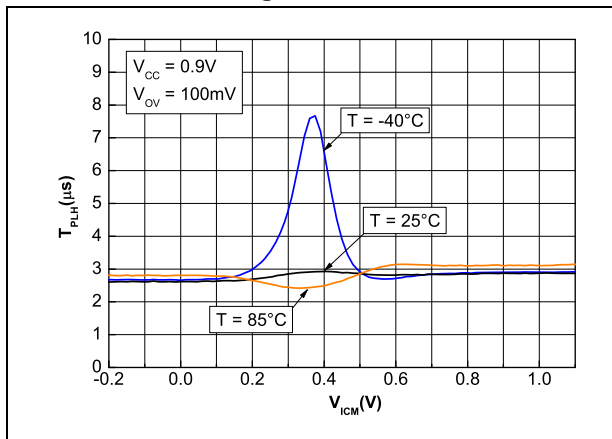
**Figure 38. Propagation delay  $T_{PLH}$  vs. input common mode voltage at  $V_{CC} = 0.9\text{ V}$  and  $10\text{ mV}$  signal overdrive**



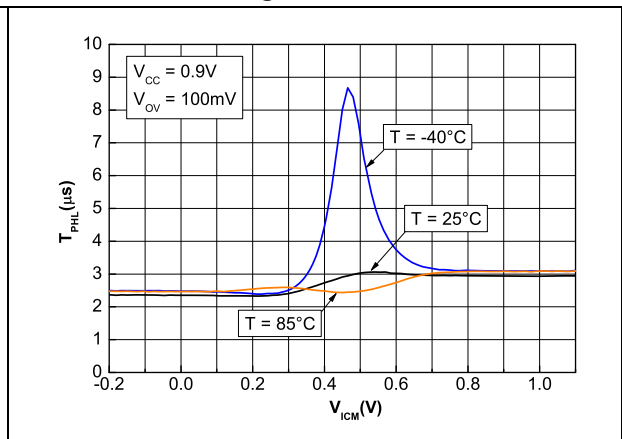
**Figure 39. Propagation delay  $T_{PHL}$  vs. input common mode voltage at  $V_{CC} = 0.9\text{ V}$  and  $10\text{ mV}$  signal overdrive**



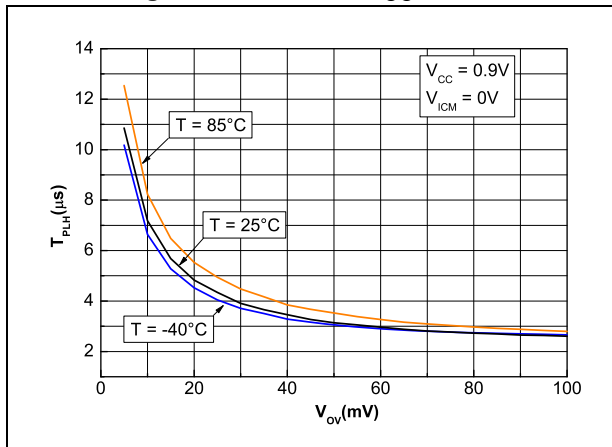
**Figure 40. Propagation delay  $T_{PLH}$  vs. input common mode voltage at  $V_{CC} = 0.9\text{ V}$  and  $100\text{ mV}$  signal overdrive**



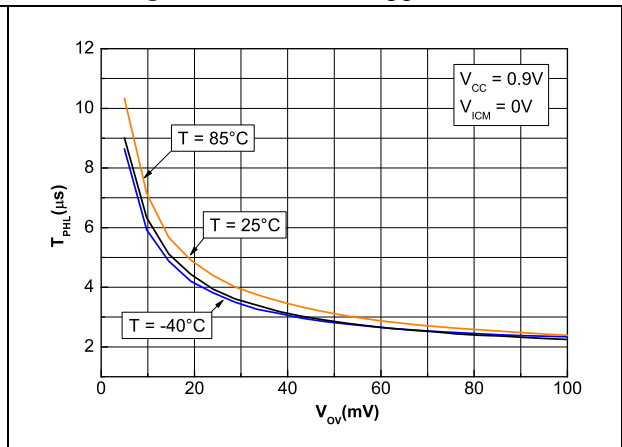
**Figure 41. Propagation delay  $T_{PHL}$  vs. input common mode voltage at  $V_{CC} = 0.9\text{ V}$  and  $100\text{ mV}$  signal overdrive**



**Figure 42. Propagation delay  $T_{PLH}$  vs. input signal overdrive at  $V_{CC} = 0.9\text{ V}$**



**Figure 43. Propagation delay  $T_{PHL}$  vs. input signal overdrive at  $V_{CC} = 0.9\text{ V}$**





### 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

Figure 44. SC70-5 (SOT323-5) package outline

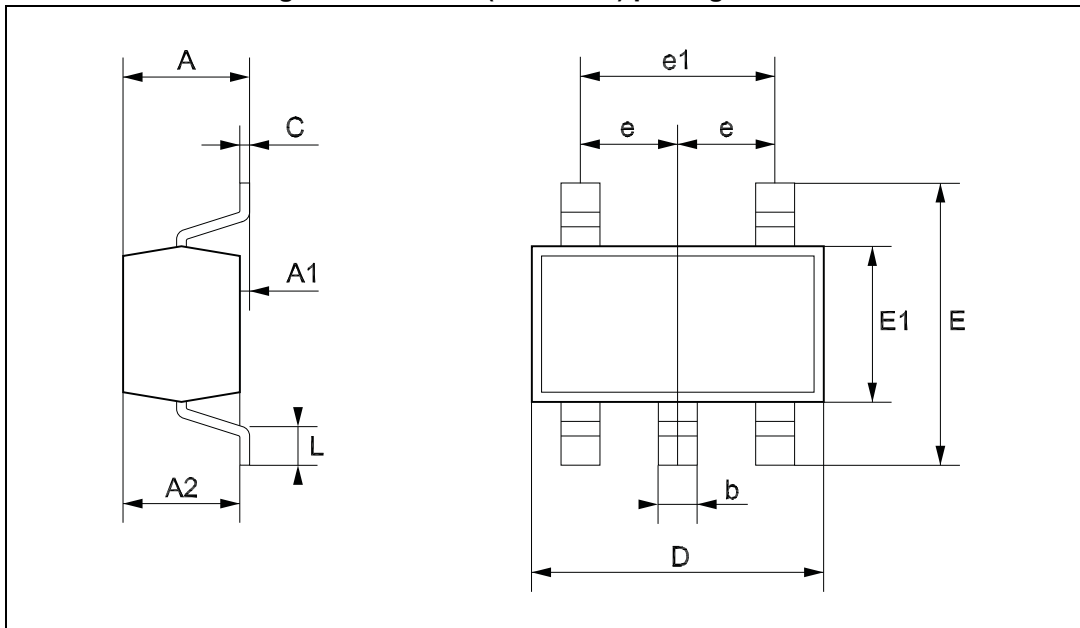


Table 7. SC70-5 (SOT323-5) package mechanical data

Symbol	Dimensions					
	Millimeters			Mils		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80		1.10	31.5		43.3
A1	0.00		0.10	0.0		3.9
A2	0.80	0.9	1.00	31.5	35.4	39.4
b	0.15		0.30	5.9		11.8
C	0.10		0.22	3.9		8.7
D	1.80		2.20	70.9		86.6
E	1.80		2.40	70.9		94.5
E1	1.15	1.25	1.35	45.3	49.2	53.1
e		0.65			25.6	
e1		1.3			51.2	
L	0.26	0.36	0.46	10.2	14.2	18.1

Figure 45. SOT23-5 - lead small outline transistor package outline

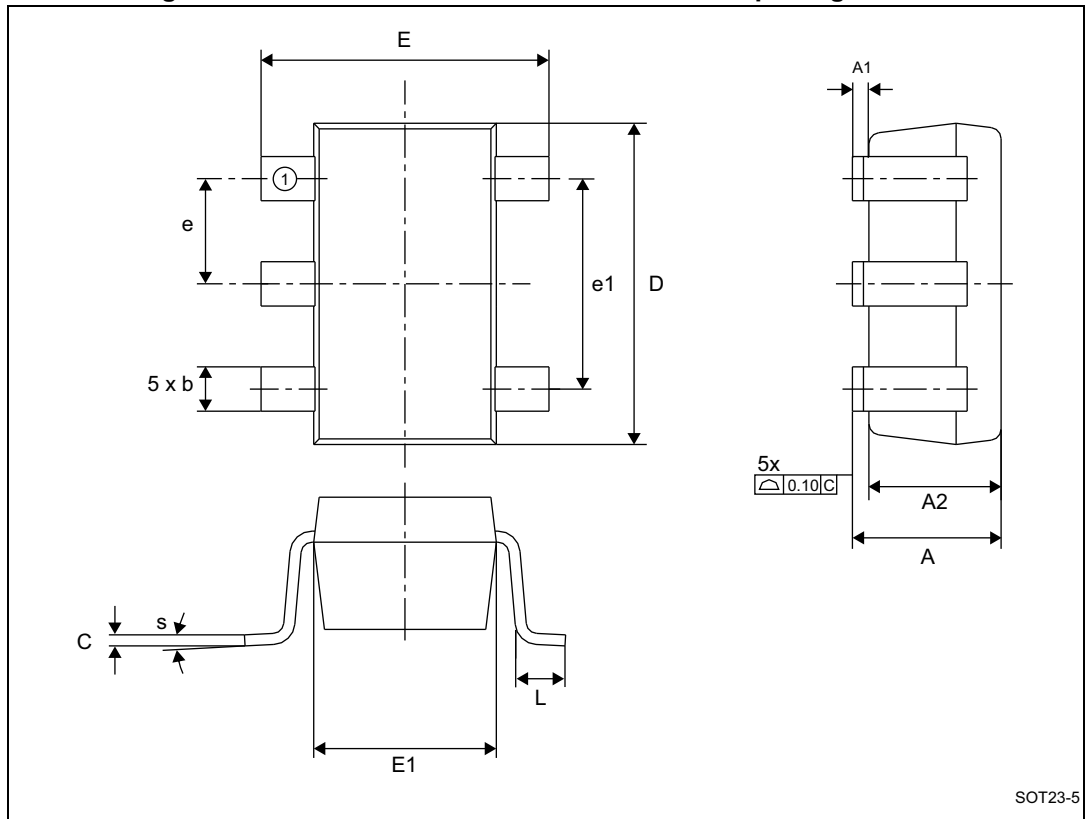


Table 8. SOT23-5 - lead small outline transistor package mechanical data

Symbol	Dimensions					
	Millimeters			Inches		
	Typ.	Min.	Max.	Typ.	Min.	Max.
A			1.45			0.057
A1		0.00	0.15		0.000	0.006
A2	1.15	0.90	1.30	0.045	0.035	0.051
b		0.30	0.50		0.012	0.020
c		0.08	0.22		0.003	0.009
D	2.90			0.114		
E	2.80			0.110		
E1	1.60			0.063		
e	0.95			0.037		
e1	1.90			0.075		
L	0.45	0.30	0.60	0.018	0.012	0.024
q	4	0	8	4	0	8
N	5			5		

## 4 Ordering information

Table 9. Order codes

Order code	Temperature range	Package	Packaging	Marking
TS881ICT	-40 to +125 °C	SC70-5	Tape and reel	K56
TS881ILT	-40 to +125 °C	SOT23-5	Tape and reel	K524

## 5 Revision history

Table 10. Document revision history

Date	Revision	Changes
18-Jul-2012	1	Initial release.
16-Dec-2013	2	<p>Updated title <a href="#">on page 1</a> (replaced 1.1 V by 0.9 V).</p> <p>Added package SOT23-5 and package information: <a href="#">on page 1</a>, in <a href="#">Section : Description on page 1, Figure 1: Pin connections (top view) on page 1, Table 1, Section 3: Package information, Section 4: Ordering information</a>.</p> <p>Updated <a href="#">Section : Features on page 1</a> (replaced “Supply operation” from “1.1 V to 5.5 V” to “0.85 V to 5.5 V”, HBM changed from 4 kV to 8 kV).</p> <p>Updated <a href="#">Section : Description on page 1</a> (replaced 1.1 by 0.85 V).</p> <p>Updated <a href="#">Table 1</a> (changed ESD HBM to 8000 V).</p> <p>Updated <a href="#">Table 2</a> (updated and added parameters and values).</p> <p>Updated <a href="#">Section 2: Electrical characteristics</a>:</p> <ul style="list-style-type: none"> <li>– Added <a href="#">Table 3</a>.</li> <li>– Updated <a href="#">Table 4, Table 5, Table 6</a> (added min. values for I<sub>IO</sub> and I<sub>IB</sub> symbols).</li> <li>– Note 4. below <a href="#">Table 4.</a>, note 4. below <a href="#">Table 5.</a>, and note 4. below <a href="#">Table 6</a> (replaced “Maximum values include unavoidable inaccuracies of the industrial tests.” by “Maximum values are guaranteed by design.”).</li> <li>– Added <a href="#">Figure 34</a> to <a href="#">Figure 43</a>.</li> </ul> <p>Minor modifications throughout document.</p>

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